

# SILICON NPN PLANAR TYPE

# 2SC2804

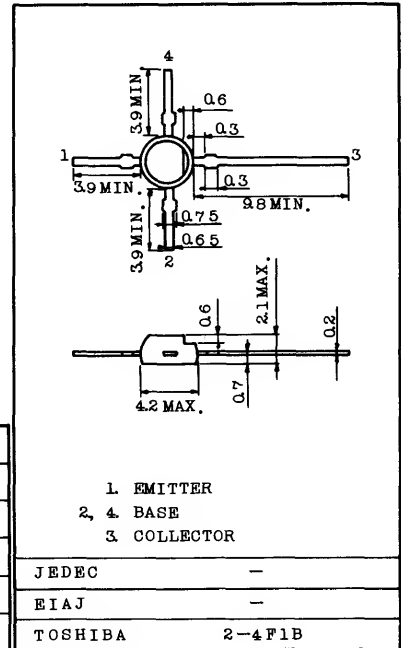
UHF TV TUNER RF AMPLIFIER APPLICATIONS.

**FEATURES:**

- . Low Noise Figure :  $NF=3.5dB(Typ.)$ ,  $f=800MHz$
- . High Power Gain :  $G_{pb}=16dB(Typ.)$ ,  $f=800MHz$
- . Excellent Forward AGC Characteristics

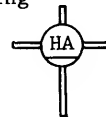
**MAXIMUM RATINGS ( $T_a=25^{\circ}C$ )**

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	$V_{CB0}$	25	V
Collector-Emitter Voltage	$V_{CE0}$	20	V
Emitter-Base Voltage	$V_{EB0}$	3	V
Base Current	$I_B$	10	mA
Collector Current	$I_C$	20	mA
Collector Power Dissipation	$P_C$	200	mW
Junction Temperature	$T_j$	125	$^{\circ}C$
Storage Temperature Range	$T_{stg}$	-55 ~ 125	$^{\circ}C$



Weight : 0.08g

Marking

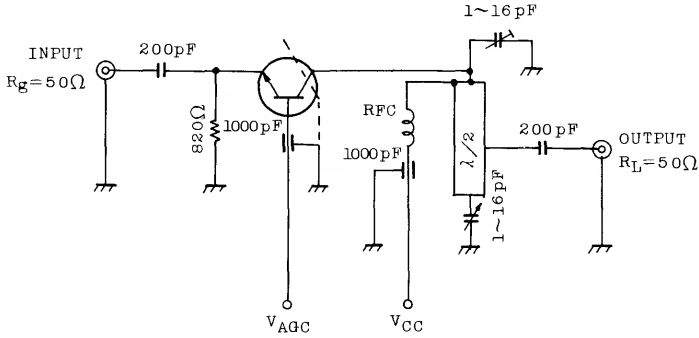


**ELECTRICAL CHARACTERISTICS ( $T_a=25^{\circ}C$ )**

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	$I_{CBO}$	$V_{CB}=10V, I_E=0$	-	-	0.1	$\mu A$
Emitter Cut-off Current	$I_{EBO}$	$V_{EB}=2V, I_C=0$	-	-	1	$\mu A$
Collector-Emitter Breakdown Voltage	$V(BR)_{CEO}$	$I_C=1mA, I_B=0$	20	-	-	V
DC Current Gain	$h_{FE}$	$V_{CE}=10V, I_C=2mA$	25	100	-	
Transition Frequency	$f_T$	$V_{CE}=10V, I_C=2mA$	600	900	-	MHz
Reverse Transfer Capacitance	$C_{rb}$	$V_{CE}=10V, I_B=0, f=1MHz$	-	0.25	0.45	pF
Power Gain	$G_{pb}$	$V_{CC}=12V, V_{AGC}=3.0V$	10	16	-	dB
Noise Figure	NF	$f=800MHz$ (Fig. 1)	-	3.5	5.5	dB
AGC Voltage	$V_{AGC}$	$V_{CC}=12V, G.R.=-20dB$ $f=800MHz$ (Fig. 1)	4.75	6.0	7.25	V

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Fig. 1 : 800MHz  $G_{pb}$ , NF, AND  $V_{AGC}$  TEST CIRCUIT



Note :  $V_{AGC}$  measured by the test circuit shown in Fig.1, when the power gain is reduced to 20dB compared with  $G_{pb}$  shown above Table.

